











uA78M05, uA78M06, uA78M08 uA78M09, uA78M10, uA78M12, uA78M33

SLVS059T - JUNE 1976-REVISED JANUARY 2015

µA78Mxx Positive-Voltage Regulators

Features

- 3-Terminal Regulators
- Output Current up to 500 mA
- No External Components
- Internal Thermal-Overload Protection
- High Power-Dissipation Capability
- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation

Applications

- On-Card Regulation
- Portable Devices
- Computing & Servers
- **Telecommunications**

3 Description

This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. The applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
	SOT-223 (3)	6.50 mm x 3.50 mm
UA78Mxx	TO-220 (3)	10.16 mm x 8.82 mm
	TO-252 (3)	6.60 mm x 6.10 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic

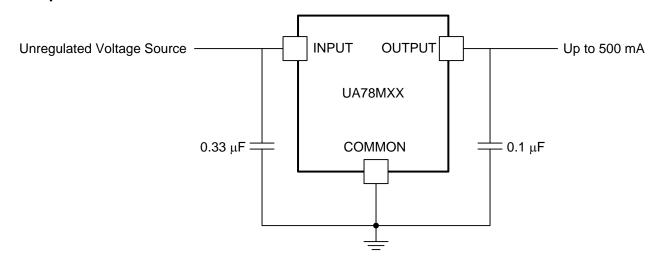




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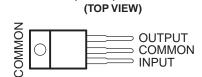
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5 Revision History

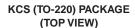
Changes from Revision S (May 2013) to Revision T Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section. Changes from Revision R (February 2013) to Revision S Page Removed Ordering Information table. 1 Changes from Revision Q (April 2010) to Revision R Page Removed obsolete part information from document.

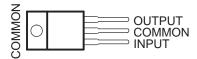


6 Pin Configuration and Functions

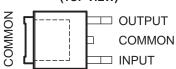


KC (TO-220) PACKAGE



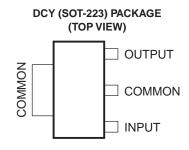


KVU (TO-252) PACKAGE (TOP VIEW)



KTP (PowerFLEX /TO-252*) PACKAGE (TOP VIEW) OUTPUT COMMON INPUT





Pin Functions

	PIN	TYPE	DESCRIPTION
NAME	NO.	ITPE	DESCRIPTION
COMMON	2	_	Ground
INPUT	1	I	Supply Input
OUTPUT	3	0	Voltage Output



7 Specifications

7.1 Absolute Maximum Ratings

over virtual junction temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
V_{I}	Input voltage		35	V
T_{J}	Operating virtual junction temperature		150	°C
T _{stg}	Storage temperature range	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	2500	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	2000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

	' 5		MIN	MAX	UNIT
		uA78M33	5.3	25	
V _I Input v		uA78M05	7	25	
		uA78M06	8	25	
	lanut valtaga	uA78M08	10.5	25	V
	uA78M09 uA78M10 uA78M12 uA78M15	uA78M09	11.5	26	
		uA78M10	12.5	28	
		uA78M12	14.5	30	
		uA78M15	17.5	30	
Io	Output current			500	mA
т	Operating virtual junction temperature	uA78MxxC	0	125	Ŝ
TJ	Operating virtual junction temperature	uA78MxxI	-40	125	C

7.4 Thermal Information

<i>.</i>								
			UA78Mxx					
	THERMAL METRIC ⁽¹⁾	DCY	KC	KCS	KTP	KVU	UNIT	
		3 PINS	3 PINS	3 PINS	3 PINS	3 PINS		
R_{\thetaJA}	Junction-to-ambient thermal resistance	53	19	19	28	30.3		
R _{θJC(to} p)	Junction-to-case (top) thermal resistance	30.6	17	17	19	_	°C/W	
R _{θJC(b} ot)	Junction-to-case (bottom) thermal resistance	_	3	3	1.4	_		

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.



7.5 Electrical Characteristics — uA78M33C

at specified virtual junction temperature, V₁ = 8 V, I₀ = 350 mA, T₁ = 25°C (unless otherwise noted)

PARAMETER0	TEST CONDITIONS ⁽¹⁾			uA ⁻	UNIT		
PARAMETERU				MIN	TYP	MAX	ONIT
Output voltage ⁽²⁾	$I_{O} = 5 \text{ mA to } 350$	mA,		3.2	3.3	3.4	V
Output voltage	$V_1 = 8 \text{ V to } 20 \text{ V}$	V _I = 8 V to 20 V	$T_J = 0$ °C to 125°C	3.1	3.3	3.5	V
Innut voltogo regulation	1 200 m A		$V_1 = 5.3 \text{ V to } 25 \text{ V}$		9	100	mV
Input voltage regulation	I _O = 200 mA		$V_{I} = 8 \text{ V to } 25 \text{ V}$		3	50	mv
Dinnle rejection	$V_1 = 8 \text{ V to } 18 \text{ V},$		$I_{O} = 100 \text{ mA}, T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$	62			dB
Ripple rejection	f = 120 Hz		I _O = 300 mA	62	80		uБ
Output voltage regulation	V _I = 8 V,		I _O = 5 mA to 500 mA		20	100	mV
Temperature coefficient of output voltage	I _O = 5 mA,		$T_J = 0$ °C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 k	:Hz			40	200	μV
Dropout voltage					2		٧
Bias current					4.5	6	mA
Dies summent about	I _O = 200 mA,	$V_I = 8 \text{ V to } 25 \text{ V},$	$T_J = 0$ °C to 125°C			0.8	A
Bias current change	$I_{O} = 5 \text{ mA to } 350$	mA,	$T_J = 0$ °C to 125°C			0.5	mA
Short-circuit output current	V _I = 35 V				300		mA
Peak output current					700		mA

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

7.6 Electrical Characteristics — uA78M33I

at specified virtual junction temperature, V_I = 8 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

DADAMETED		TEST CONDIT	20NC(1)	uA	78M33		LINUT
PARAMETER		IEST CONDIT	ions	MIN	TYP	MAX	UNIT
Output voltage ⁽²⁾	I _O = 5 mA to 350 m	nA,		3.2	3.3	3.4	V
Output Voltage V	$V_1 = 8 \text{ V to } 20 \text{ V}$		$T_J = -40$ °C to 125°C	3.1	3.3	3.5	V
Input voltage regulation	I - 200 mA		$V_{I} = 5.3 \text{ V to } 25 \text{ V}$		9	100	mV
Input voltage regulation	I _O = 200 mA		$V_I = 8 V \text{ to } 25 V$		3	50	IIIV
Ripple rejection	V _I = 8 V to 18 V,		I_O = 100 mA, T_J = -40°C to 125°C	62			dB
	f = 120 Hz		I _O = 300 mA	62	80		
Output voltage regulation	$V_{I} = 8 V,$		$I_O = 5$ mA to 500 mA		20	100	mV
Temperature coefficient of output voltage	I _O = 5 mA,		$T_{J} = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kl	Нz			40	200	μV
Dropout voltage					2		V
Bias current					4.5	6	mA
Pice current change	$I_O = 200 \text{ mA},$	$V_1 = 8 V \text{ to } 25 V,$	$T_J = -40$ °C to 125°C			8.0	mA
Bias current change	I _O = 5 mA to 350 mA,		$T_J = -40$ °C to 125°C			0.5	ША
Short-circuit output current	V _I = 35 V				300		mA
Peak output current		·			700		mA

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

⁽²⁾ This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.

⁽²⁾ This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.



7.7 Electrical Characteristics — uA78M05C

at specified virtual junction temperature, V_I = 10 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

DADAMETED	T-0	TEST CONDITIONS ⁽¹⁾			;	LINUT
PARAMETER	IES				MAX	UNIT
Output voltage ⁽²⁾	I _O = 5 mA to 350 mA,		4.8	5	5.2	V
Output voitage	$V_I = 7 \text{ V to } 20 \text{ V}$	$T_J = 0$ °C to 125°C	4.75		5.25	V
land traite as we will the	1 200 m A	$V_I = 7 \text{ V to } 25 \text{ V}$		3	100	\/
Input voltage regulation	I _O = 200 mA	V _I = 8 V to 25 V		1	50	mV
Dinale rejection	V _I = 8 V to 18 V,	I _O = 100 mA, T _J = 0°C to 125°C	62			dB
Ripple rejection	f = 120 Hz	I _O = 300 mA	62	80		ав
Output welters as as suleties	I _O = 5 mA to 500 mA			20	100	\/
Output voltage regulation	I _O = 5 mA to 200 mA			10	50	mV
Temperature coefficient of output voltage	I _O = 5 mA,	T _J = 0°C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2		V
Bias current				4.5	6	mA
D'an annual al annual	$I_O = 200 \text{ mA}, V_I = 8 \text{ V to } 25 \text{ V}$	V, T _J = 0°C to 125°C			0.8	1
Bias current change	$I_O = 5 \text{ mA to } 350 \text{ mA},$	$T_J = 0$ °C to 125°C			0.5	mA
Short-circuit output current	V _I = 35 V			300		mA
Peak output current				0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

7.8 Electrical Characteristics — uA78M05I

at specified virtual junction temperature, $V_1 = 10 \text{ V}$, $I_0 = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾			478M0	51	UNIT
PARAMETER	TEST CONDI	IIIONS	MIN	TYP	MAX	UNII
Output voltage ⁽²⁾	I _O = 5 mA to 350 mA,		4.8	5	5.2	V
Output voltage	$V_I = 7 \text{ V to } 20 \text{ V}$	$T_J = -40$ °C to 125°C	4.75		5.25	V
	J 200 m A	$V_I = 7 \text{ V to } 25 \text{ V}$		3	100	\/
Input voltage regulation	I _O = 200 mA	V _I = 8 V to 25 V		1	50	mV
Dinale rejection	V _I = 8 V to 18 V,	$I_O = 100 \text{ mA}, T_J = -40^{\circ}\text{C to } 125^{\circ}\text{C}$	62			-10
Ripple rejection	f = 120 Hz	I _O = 300 mA	62	80		dB
Output voltage	I _O = 5 mA to 500 mA			20	100	\/
regulation	I _O = 5 mA to 200 mA			10	50	mV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = -40$ °C to 125°C		-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz			40	200	μV
Dropout voltage				2		٧
Bias current				4.5	6	mA
Dies summent about	$I_O = 200 \text{ mA}, \qquad V_I = 8 \text{ V to } 25 \text{ V},$	$T_{J} = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$			0.8	Λ
Bias current change	I _O = 5 mA to 350 mA,	$T_{J} = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$			0.5	mA
Short-circuit output current	V _I = 35 V			300		mA
Peak output current				0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

⁽²⁾ This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.

⁽²⁾ This specification applies only for dc power dissipation permitted by *Absolute Maximum Ratings*.



7.9 Electrical Characteristics — uA78M06C

at specified virtual junction temperature, V_I = 11 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

DADAMETED	TEST CONDITIONS ⁽¹⁾			uA	uA78M06C		
PARAMETER	TEST CONDITIONS(*)				TYP	MAX	UNIT
Output voltage ⁽²⁾	$I_0 = 5 \text{ mA to } 350 \text{ mA},$	$V_1 = 8 \text{ V to } 21 \text{ V}$		5.75	6	6.25	V
Output voitage	1 ₀ = 5 IIIA to 350 IIIA,	V ₁ = 0 V 10 21 V	$T_J = 0$ °C to 125°C	5.7		6.3	V
Innut voltage regulation	1 200 m A	$V_{I} = 8 \text{ V to } 25 \text{ V}$			5	100	mV
Input voltage regulation	I _O = 200 mA	$V_{I} = 9 V \text{ to } 25 V$			1.5	50	IIIV
Ripple rejection	V _I = 8 V to 18 V,	f = 120 Hz	$I_{O} = 100 \text{ mA},$ $T_{J} = 0^{\circ}\text{C to } 125^{\circ}\text{C}$	59			dB
			$I_0 = 300 \text{ mA}$	59	80		
Output voltage regulation	$I_O = 5$ mA to 500 mA				20	120	mV
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	60	IIIV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				45		μV
Dropout voltage					2		V
Bias current					4.5	6	mA
Dies surrent change	$V_{I} = 9 V \text{ to } 25 V,$	$I_O = 200 \text{ mA},$	$T_J = 0$ °C to 125°C			0.8	mA
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	IIIA
Short-circuit output current	V _I = 35 V				270		mA
Peak output current					0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

7.10 Electrical Characteristics — uA78M08C

at specified virtual junction temperature, $V_1 = 14 \text{ V}$, $I_0 = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		uA	78M08	3C	LINUT
PARAIVIETER		TEST CONDITIONS.		MIN	TYP	MAX	UNIT
Output voltage ⁽²⁾	V = 10 5 V to 22 V	l − Ε mΛ to 3Ε0 mΛ		7.7	8	8.3	V
Output Voltage V	$V_I = 10.5 \text{ V to } 23 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	7.6		8.4	V
lanut valtage regulation	1 200 m A	$V_I = 10.5 \text{ V to } 25 \text{ V}$			6	100	mV
Input voltage regulation	I _O = 200 mA	$V_{I} = 11 \text{ V to } 25 \text{ V}$			2	50	IIIV
Dinale rejection	$V_I = 11 \text{ V to } 21.5 \text{ V},$	$I_{O} = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	56			dB
Ripple rejection	f = 120 Hz	$I_O = 300 \text{ mA}$		56	80		uБ
Output valtage regulation	$I_O = 5$ mA to 500 mA				25	160	\/
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	80	mV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				52		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Dies sument shares	V _I = 10.5 V to 25 V,	I _O = 200 mA,	T _J = 0°C to 125°C			0.8	A
Bias current change	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				250		mA
Peak output current					0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

⁽²⁾ This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.

⁽²⁾ This specification applies only for dc power dissipation permitted by *Absolute Maximum Ratings*.



7.11 Electrical Characteristics — uA78M09C

at specified virtual junction temperature, V_I = 16 V, I_O = 350 mA, T_J = 25°C (unless otherwise noted)

DADAMETED		TEST CONDITIONS(1)		uA	78M09	C	LINUT
PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
Output voltage ⁽²⁾	V = 11 5 V to 24 V	L = Ε mΛ to 250 mΛ		8.6	9	9.4	V
Output voltage -	$V_I = 11.5 \text{ V to } 24 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	T _J = 0°C to 125°C	8.5		9.5	V
Innut voltogo regulation	1 200 m A	$V_I = 11.5 \text{ V to } 26 \text{ V}$			6	100	mV
Input voltage regulation	I _O = 200 mA	$V_1 = 12 \text{ V to } 26 \text{ V}$			2	50	mv
Ripple rejection	V _I = 13 V to 23 V,	$I_{O} = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	56			dB
Rippie rejection	f = 120 Hz	$I_{O} = 300 \text{ mA}$		56	80		uБ
Output valtage regulation	$I_O = 5$ mA to 500 mA				25	180	mV
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	90	mv
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				58		μV
Dropout voltage					2		V
Bias current					4.6	6	mA
Diag ourrent change	$V_I = 11.5 \text{ V to } 26 \text{ V},$	$I_0 = 200 \text{ mA},$	$T_J = 0$ °C to 125°C			8.0	A
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				250		mA
Peak output current					0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

7.12 Electrical Characteristics — uA78M10C

at specified virtual junction temperature, $V_1 = 17 \text{ V}$, $I_0 = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		uA	78M10	C	LINIT
PARAMETER		1E21 CONDITIONS		MIN	TYP	MAX	UNIT
Output voltage ⁽²⁾	V _I = 12.5 V to 25 V,	l − 5 mΛ to 350 mΛ		9.6	10	10.4	V
Output voltage —	$V_1 = 12.5 \text{ V } 10.25 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	9.5		10.5	V
Input voltage regulation	1 200 m A	$V_I = 12.5 \text{ V to } 28 \text{ V}$			7	100	mV
Input voltage regulation	I _O = 200 mA	$V_1 = 14 \text{ V to } 28 \text{ V}$			2	50	IIIV
Dinale rejection	$V_{I} = 15 \text{ V to } 25 \text{ V},$	$I_0 = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	59			dB
Ripple rejection	f = 120 Hz	$I_O = 300 \text{ mA}$		55	80		uБ
Output valtage regulation	$I_O = 5$ mA to 500 mA				25	200	m)/
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	100	mV
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				64		μV
Dropout voltage					2		V
Bias current					4.7	6	mA
Diag summent shapes	V _I = 12.5 V to 28 V,	I _O = 200 mA,	$T_J = 0$ °C to 125°C			0.8	A
Bias current change	$I_{O} = 5 \text{ mA to } 350 \text{ mA},$	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				245		mA
Peak output current					0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

⁽²⁾ This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.

⁽²⁾ This specification applies only for dc power dissipation permitted by *Absolute Maximum Ratings*.



7.13 Electrical Characteristics — uA78M12C

at specified virtual junction temperature, $V_1 = 19 \text{ V}$, $I_0 = 350 \text{ mA}$, $T_J = 25^{\circ}\text{C}$ (unless otherwise noted)

DADAMETED		TEST CONDITIONS(1)		uA	78M12	2C	
PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
Output voltage ⁽²⁾	\/ - 14 5 \/ +0 27 \/	I − Ε mΛ to 2Ε0 mΛ		11.5	12	12.5	V
Output voltage (=/	$V_{I} = 14.5 \text{ V to } 27 \text{ V},$	$I_O = 5 \text{ mA to } 350 \text{ mA}$	$T_J = 0$ °C to 125°C	11.4		12.6	V
Innut voltogo regulation	1 200 m A	$V_I = 14.5 \text{ V to } 30 \text{ V}$			8	100	mV
Input voltage regulation	I _O = 200 mA	$V_{I} = 16 \text{ V to } 30 \text{ V}$			2	50	
Dinnle rejection	$V_1 = 15 \text{ V to } 25 \text{ V},$	$I_{O} = 100 \text{ mA},$	$T_J = 0$ °C to 125°C	55			dB
Ripple rejection	f = 120 Hz	$I_{O} = 300 \text{ mA}$		55	80		ub
Output valtage regulation	$I_O = 5$ mA to 500 mA				25	240	mV
Output voltage regulation	$I_O = 5$ mA to 200 mA				10	120	
Temperature coefficient of output voltage	I _O = 5 mA,	$T_J = 0$ °C to 125°C			-1		mV/°C
Output noise voltage	f = 10 Hz to 100 kHz				75		μV
Dropout voltage					2		V
Bias current					4.8	6	mA
Dies summent about	$V_I = 14.5 \text{ V to } 30 \text{ V},$	I _O = 200 mA,	$T_J = 0$ °C to 125°C			0.8	A
Bias current change	$I_O = 5$ mA to 350 mA,	$T_J = 0$ °C to 125°C				0.5	mA
Short-circuit output current	V _I = 35 V				240		mA
Peak output current					0.7		Α

⁽¹⁾ All characteristics are measured with a 0.33-μF capacitor across the input and a 0.1-μF capacitor across the output. Pulse-testing techniques maintain T_J as close to T_A as possible. Thermal effects must be taken into account separately.

7.14 Typical Characteristics

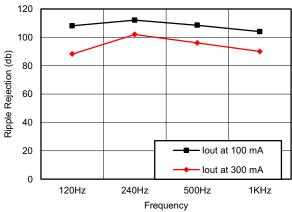


Figure 1. Ripple Rejection vs Frequency V_INPUT = 8 V to 18 V, TA = 25°C

⁽²⁾ This specification applies only for dc power dissipation permitted by Absolute Maximum Ratings.

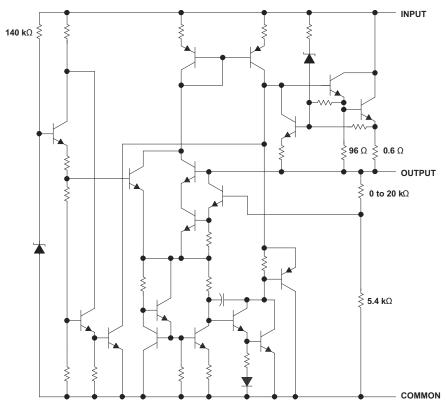


8 Detailed Description

8.1 Overview

This series of fixed-voltage integrated-circuit voltage regulators is designed for a wide range of applications. The applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. Each of these regulators can deliver up to 500 mA of output current. The internal current-limiting and thermal-shutdown features of these regulators essentially make them immune to overload. In addition to use as fixed-voltage regulators, these devices can be used with external components to obtain adjustable output voltages and currents and also as the power-pass element in precision regulators.

8.2 Functional Block Diagram



Resistor values shown are nominal

8.3 Feature Description

- 3-Terminal Regulators
- Output Current up to 500 mA
- No External Components
- Internal Thermal-Overload Protection
- High Power-Dissipation Capability
- Internal Short-Circuit Current Limiting
- Output Transistor Safe-Area Compensation

8.4 Device Functional Modes

8.4.1 Fixed-Output Mode

These devices are available in fixed-output voltages. See the orderable part list for the desired output.



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The UA78Mxx devices are ideal for use as linear regulators with few external components needed for a working design. They are also useful for attenuating power supply noise.

9.2 Typical Application

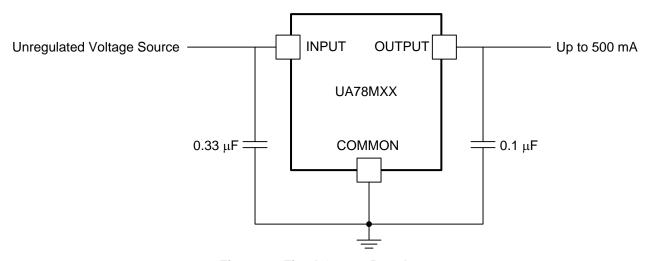


Figure 2. Fixed-Output Regulator

9.2.1 Design Requirements

An 0.33-µF decoupling capacitor on the input and a 0.1-µF decoupling capacitor on the output are recommended for the UA78Mxx to behave as close to datasheet specifications as possible.

9.2.2 Detailed Design Procedure

The customer's end application will determine how the schematic for UA78Mxx is designed. For example, if there is a load connected to a negative voltage as its ground, a clamp diode may be necessary on the output. In the event of an input short circuit or another case where the output voltage can be higher than the input, a diode shunt can be connected across the device with the anode at the output and cathode at the input



Typical Application (continued)

9.2.3 Application Curves

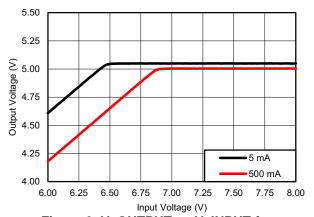


Figure 3. V_OUTPUT vs V_INPUT for $I_{OUTPUT} = 5$ mA and 500 mA (25°C)



10 Power Supply Recommendations

See *Recommended Operating Conditions* for the recommended power supply voltages for each variation of the UA78Mxx. Different orderable part numbers will be able to tolerate different levels of voltage. It is also recommended to have a decoupling capacitor on the output to limit noise on the input.

11 Layout

11.1 Layout Guidelines

Keep trace widths large enough to eliminate problematic IxR voltage drops at the input and output terminals. Input decoupling capacitors should be placed as close to the UA78MXX as possible.

11.2 Layout Example

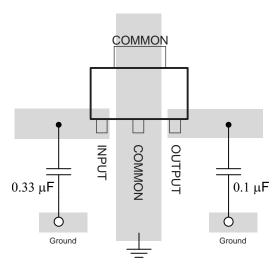


Figure 4. Layout Diagram



12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
uA78M05	Click here	Click here	Click here	Click here	Click here
uA78M06	Click here	Click here	Click here	Click here	Click here
uA78M08	Click here	Click here	Click here	Click here	Click here
uA78M09	Click here	Click here	Click here	Click here	Click here
uA78M10	Click here	Click here	Click here	Click here	Click here
uA78M12	Click here	Click here	Click here	Click here	Click here
uA78M33	Click here	Click here	Click here	Click here	Click here

12.2 Trademarks

All trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Submit Documentation Feedback





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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
SN78MCDCYR	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C5	Sample
UA78M05CDCY	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C5	Sample
UA78M05CDCYG3	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR 0 to 125		C5	Sampl
UA78M05CDCYR	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C5	Sampl
UA78M05CDCYRG3	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C5	Sampl
UA78M05CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M05C	Sampl
UA78M05CKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M05C	Sampl
UA78M05CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M05C	Sampl
UA78M05IDCY	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	J5	Samp
UA78M05IDCYG3	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	J5	Sampl
UA78M05IDCYR	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	J5	Samp
UA78M05IDCYRG3	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	-40 to 125	J5	Samp
UA78M05IKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	-40 to 125	UA78M05I	Samp
UA78M05IKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	-40 to 125	UA78M05I	Samp
UA78M05IKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 125	78M05I	Samp
UA78M06CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR 0 to 125		78M06C	Samp
UA78M08CDCY	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C8	Samp



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Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
UA78M08CDCYG3	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08CDCYR	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C8	Samples
UA78M08CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M08C	Samples
UA78M08CKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M08C	Samples
UA78M08CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M08C	Samples
UA78M09CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M09C	Samples
UA78M10CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M10C	Samples
UA78M12CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M12C	Samples
UA78M12CKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M12C	Samples
UA78M12CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M12C	Samples
UA78M33CDCY	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CDCYG3	ACTIVE	SOT-223	DCY	4	80	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CDCYR	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CDCYRG3	ACTIVE	SOT-223	DCY	4	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	C3	Samples
UA78M33CKCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M33C	Samples
UA78M33CKCSE3	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	0 to 125	UA78M33C	Samples
UA78M33CKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	0 to 125	78M33C	Samples
UA78M33IKVURG3	ACTIVE	TO-252	KVU	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-3-260C-168 HR	-40 to 125	78M33I	Samples

PACKAGE OPTION ADDENDUM



15-Apr-2017

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF UA78M05, UA78M33:

Automotive: UA78M05-Q1, UA78M33-Q1



PACKAGE OPTION ADDENDUM

15-Apr-2017

NOTE: Qualified Version Definition:	VO.	TE: C	Dualified	Version	Definitions
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• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



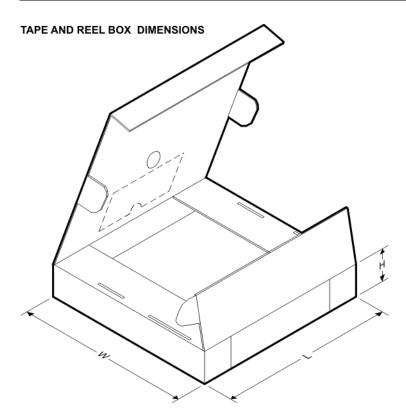
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UA78M05CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.0	7.42	2.0	8.0	12.0	Q3
UA78M05CDCYR	SOT-223	DCY	4	2500	330.0	12.4	6.55	7.25	1.9	8.0	12.0	Q3
UA78M05CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M05CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M05IDCYR	SOT-223	DCY	4	2500	330.0	12.4	6.55	7.25	1.9	8.0	12.0	Q3
UA78M05IDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.0	7.42	2.0	8.0	12.0	Q3
UA78M05IDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M05IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M05IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M06CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M08CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.0	7.42	2.0	8.0	12.0	Q3
UA78M08CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3
UA78M08CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M09CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M10CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M10CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M12CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M33CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.05	7.4	1.9	8.0	12.0	Q3

PACKAGE MATERIALS INFORMATION

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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UA78M33CDCYR	SOT-223	DCY	4	2500	330.0	12.4	7.0	7.42	2.0	8.0	12.0	Q3
UA78M33CDCYR	SOT-223	DCY	4	2500	330.0	12.4	6.55	7.25	1.9	8.0	12.0	Q3
UA78M33CKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
UA78M33IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.8	8.0	16.0	Q2
UA78M33IKVURG3	TO-252	KVU	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UA78M05CDCYR	SOT-223	DCY	4	2500	350.0	334.0	47.0
UA78M05CDCYR	SOT-223	DCY	4	2500	336.0	336.0	48.0
UA78M05CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M05CKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M05IDCYR	SOT-223	DCY	4	2500	336.0	336.0	48.0
UA78M05IDCYR	SOT-223	DCY	4	2500	350.0	334.0	47.0
UA78M05IDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M05IKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M05IKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M06CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M08CDCYR	SOT-223	DCY	4	2500	350.0	334.0	47.0
UA78M08CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0



PACKAGE MATERIALS INFORMATION

www.ti.com 3-Aug-2017

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UA78M08CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M09CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M10CKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M10CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M12CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M33CDCYR	SOT-223	DCY	4	2500	340.0	340.0	38.0
UA78M33CDCYR	SOT-223	DCY	4	2500	350.0	334.0	47.0
UA78M33CDCYR	SOT-223	DCY	4	2500	336.0	336.0	48.0
UA78M33CKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0
UA78M33IKVURG3	TO-252	KVU	3	2500	350.0	334.0	47.0
UA78M33IKVURG3	TO-252	KVU	3	2500	340.0	340.0	38.0

DCY (R-PDSO-G4)

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters (inches).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion.

D. Falls within JEDEC TO-261 Variation AA.

DCY (R-PDSO-G4)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil recommendations. Refer to IPC 7525 for stencil design considerations.







NOTES:

- 1. Dimensions are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Reference JEDEC registration TO-220.







Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4205521-2/E







NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. Shape may vary per different assembly sites.

 4. Reference JEDEC registration TO-252.





NOTES: (continued)

- 5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).
- 6. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.





NOTES: (continued)



^{7.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations

design recommendations.

8. Board assembly site may have different recommendations for stencil design.

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